

INCHANGE SEMICONDUCTOR

isc N-Channel Mosfet Transistor

BUZ40B

• FEATURES

- SOA is Power Dissipation Limited
- Nanosecond Switching Speeds
- Linear Transfer Characteristics
- High speed switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

• Designed for applications such as switching regulators, switching converters, motor drivers, relay drivers and drivers for high power bipolar switching transistors requiring high speed and low gate drive power. This type can be operated directly from integrated circuits.

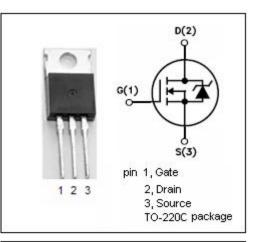
SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	500	V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-continuous@ TC=35°C	8.5	А
I _{DM}	Drain Current-Single Plused	34	А
P _{tot}	Total Dissipation@TC=25°C	150	W
Tj	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C

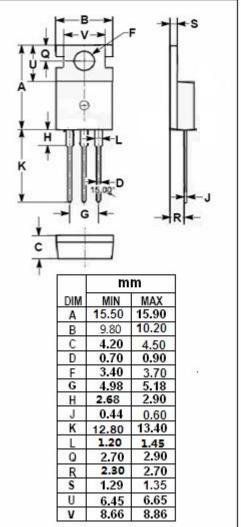
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.83	°C/W
Rth j-a	Thermal Resistance, Junction to Ambient	75	°C/W

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =0.25mA	500			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1mA	2.1		4.0	V
V_{SD}	Diode Forward On-voltage	I _S = 20A ;V _{GS} = 0			1.3	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 5.5A			0.8	Ω
IGSS	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =500V; V _{GS} = 0			1	μA
Gfs	Forward Transconductance	V _{DS} = 25V; I _D =5.5A	5.0			S
t _{d(on)}	Turn-on Delay Time	V _{GS} =10V;			30	
tr	Rise Time	I _D =3A;			110	
$t_{\text{d(off)}}$	Turn-off Delay Time	ປ _{DD} =30V; R _{GS} =50 Ω			340	ns
t _f	Fall Time				100	

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